2SD2457

Silicon NPN epitaxial planar type

For low-frequency output amplification

■ Features

- High collector-emitter voltage (Base open) V_{CEO}
- Low collector power dissipation P_C
- Mini Power type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit | |
|---------------------------------------|------------------|-------------|------|--|
| Collector-base voltage (Emitter open) | V _{CBO} | 50 | V | |
| Collector-emitter voltage (Base open) | V _{CEO} | 40 | V | |
| Emitter-base voltage (Collector open) | V_{EBO} | 5 | V | |
| Collector current | I_C | 1.5 | A | |
| Peak collector current | I_{CP} | 3 | А | |
| Collector power dissipation * | P _C | 1 | W | |
| Junction temperature | T_j | 150 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |

Note) *: Printed circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion

Unit: mm 4.5±0.1 1.6±0.2 1.5±0.1 0.4±0.08 1.5±0.1 1

Marking Symbol: 1Y

■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

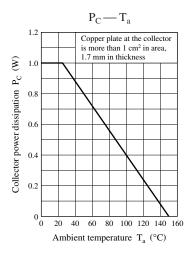
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------------------|---|-----|-----|-----|------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_C = 1 \text{ mA}, I_E = 0$ | 50 | | | V |
| Collector-emitter voltage (Base open) | V _{CEO} | $I_C = 2 \text{ mA}, I_B = 0$ | 40 | | | V |
| Collector-base cutoff current (Emitter open) | I _{CBO} | $V_{CB} = 20 \text{ V}, I_{E} = 0$ | | | 1 | μΑ |
| Collector-emitter cutoff current (Base open) | I_{CEO} | $V_{CE} = 10 \text{ V}, I_{B} = 0$ | | | 100 | μΑ |
| Emitter-base cutoff current (Collector open) | I_{EBO} | $V_{EB} = 5 \text{ V}, I_{E} = 0$ | | | 10 | μΑ |
| Forward current transfer ratio *1, 2 | h _{FE} | $V_{CE} = 5 \text{ V}, I_{C} = 1 \text{ A}$ | 80 | 120 | 220 | _ |
| Collector-emitter saturation voltage *1 | V _{CE(sat)} | $I_C = 1.5 \text{ A}, I_B = 0.15 \text{ A}$ | | | 1.0 | V |
| Base-emitter saturation voltage *1 | V _{BE(sat)} | $I_C = 2 \text{ A}, I_B = 0.2 \text{ A}$ | | | 1.5 | V |
| Transition frequency *1 | f_T | $V_{CB} = 5 \text{ V}, I_{E} = -0.5 \text{ A}, f = 200 \text{ MHz}$ | | 150 | | MHz |
| Collector output capacitance | C _{ob} | $V_{CB} = 20 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$ | | 45 | | pF |
| (Common base, input open circuited) | | | | | | |

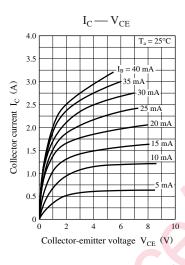
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

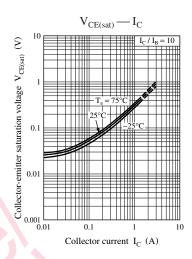
2. *1: Pulse measurement

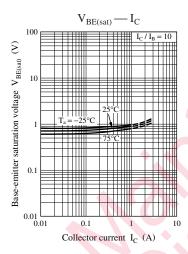
*2: Rank classification

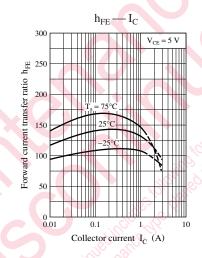
| Rank | Q | R |
|----------|-----------|------------|
| h_{FE} | 80 to 160 | 120 to 220 |

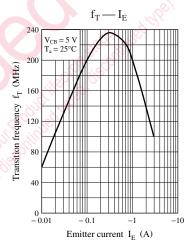


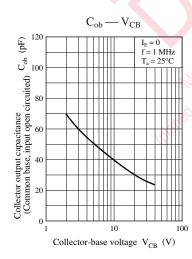












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